

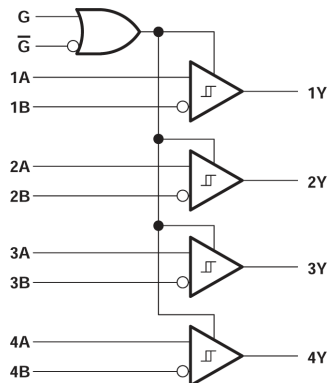
# SN65LBC173A, SN75LBC173A Quadruple RS-485 Differential Line Receivers

## 1 Features

- Designed for TIA/EIA-485, TIA/EIA-422, and ISO 8482 Applications
- Signaling Rate<sup>†</sup> Exceeding 50 Mbps
- Fail-Safe in Bus Short-Circuit, Open-Circuit, and Idle-Bus Conditions
- ESD Protection on Bus Inputs Exceeds 6 kV
- Common-Mode Bus Input Range –7 V to 12 V
- Propagation Delay Times <16 ns
- Low Standby Power Consumption <20  $\mu$ A
- Pin-Compatible Upgrade for AM26LS32, DS96F173, LTC488, and SN75173

## 2 Applications

- Factory automation
- ATM and cash counters
- Smart grid
- AC and servo motor drives



Logic Diagram

## 3 Description

The SN65LBC173A and SN75LBC173A are quadruple differential line receivers with 3-state outputs, designed for TIA/EIA-485 (RS-485), TIA/EIA-422 (RS-422), and ISO 8482 (Euro RS-485) applications.

These devices are optimized for balanced multipoint bus communication at data rates up to and exceeding 50 million bits per second. The transmission media may be twisted-pair cables, printed-circuit board traces, or backplanes. The ultimate rate and distance of data transfer is dependent upon the attenuation characteristics of the media and the noise coupling to the environment.

Each receiver operates over a wide range of positive and negative common-mode input voltages, and features ESD protection to 6 kV, making it suitable for high-speed multipoint data transmission applications in harsh environments. These devices are designed using LinBiCMOS<sup>™</sup>, facilitating low power consumption and robustness.

The G and  $\bar{G}$  inputs provide enable control logic for either positive- or negative-logic enabling all four drivers. When disabled or powered off, the receiver inputs present a high-impedance to the bus for reduced system loading.

The SN75LBC173A is characterized for operation over the temperature range of 0°C to 70°C. The SN65LBC173A is characterized over the temperature range from –40°C to 85°C.

### Package Information

| PART NUMBER | PACKAGE <sup>(1)</sup> | PACKAGE SIZE <sup>(2)</sup> |
|-------------|------------------------|-----------------------------|
| SN65LBC173A | SOIC (D, 16)           | 9.9 mm × 6 mm               |
| SN75LBC173A | PDIP (N, 16)           | 19.3 mm × 9.4 mm            |

(1) For more information, see [Section 11](#).

(2) The package size (length × width) is a nominal value and includes pins, where applicable.

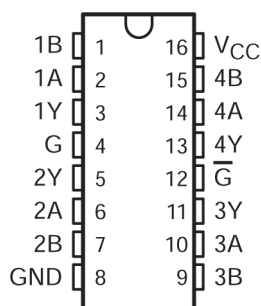
<sup>†</sup> The signaling rate of a line is the number of voltage transitions that are made per second expressed in the units bps (bits per second).



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## 4 Pin Configuration and Functions



**Figure 4-1. SN65LBC173A (Marked as 65LBC173A)  
SN75LBC173A (Marked as 75LBC173A)  
D or N Package (Top View)**

**Table 4-1. Pin Functions**

| PIN             |     | TYPE <sup>(1)</sup> | DESCRIPTION                                |
|-----------------|-----|---------------------|--------------------------------------------|
| NAME            | NO. |                     |                                            |
| 1B              | 1   | I                   | Channel 1 Inverting Differential Input     |
| 1A              | 2   | I                   | Channel 1 Non-Inverting Differential Input |
| 1Y              | 3   | O                   | Channel 1 Output                           |
| G               | 4   | I                   | Active High Receiver Enable                |
| 2Y              | 5   | O                   | Channel 2 Output                           |
| 2A              | 6   | I                   | Channel 2 Non-Inverting Differential Input |
| 2B              | 7   | I                   | Channel 2 Inverting Differential Input     |
| GND             | 8   | GND                 | Device Ground                              |
| 3B              | 9   | I                   | Channel 3 Inverting Differential Input     |
| 3A              | 10  | I                   | Channel 3 Non-Inverting Differential Input |
| 3Y              | 11  | O                   | Channel 3 Output                           |
| $\overline{G}$  | 12  | I                   | Active Low Receiver Enable                 |
| 4Y              | 13  | O                   | Channel 4 Output                           |
| 4A              | 14  | I                   | Channel 4 Non-Inverting Differential Input |
| 4B              | 15  | I                   | Channel 4 Inverting Differential Input     |
| V <sub>CC</sub> | 16  | POW                 | Device Supply                              |

(1) Signal Types: I = Input, O = Output, I/O = Input or Output.

## 5 Specifications

### 5.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)<sup>(1)</sup>

|                 |                                                                                                 | MIN                                | MAX                   | UNIT |
|-----------------|-------------------------------------------------------------------------------------------------|------------------------------------|-----------------------|------|
| V <sub>CC</sub> | Supply voltage range (see <a href="#">Note 1</a> )                                              | -0.3                               | 6                     | V    |
|                 | Voltage range at any bus input (DC)                                                             | -10                                | 15                    | V    |
|                 | Voltage range at any bus input (transient pulse through 100 Ω, see <a href="#">Figure 6-5</a> ) | -30                                | 30                    | V    |
| V <sub>I</sub>  | Voltage input range at G and G                                                                  | -0.5                               | V <sub>CC</sub> + 0.5 | V    |
| I <sub>O</sub>  | Receiver output current                                                                         |                                    | ±10                   | mA   |
|                 | Continuous power dissipation                                                                    | See Power Dissipation Rating Table |                       |      |

- (1) Stresses beyond those listed under “absolute maximum ratings” may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under “recommended operating conditions” is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
- (2) All voltage values, except differential I/O bus voltages, are with respect to GND, and are steady-state (unless otherwise specified).

### 5.2 ESD Ratings

|                    |                         |                                                                       | VALUE          | UNIT  |
|--------------------|-------------------------|-----------------------------------------------------------------------|----------------|-------|
| V <sub>(ESD)</sub> | Electrostatic discharge | Human-body model (HBM), per ANSI/ESDA/JEDEC JS-001 <sup>(1)</sup>     | A and B to GND | ±6000 |
|                    |                         |                                                                       | All pins       | ±5000 |
|                    |                         | Charged device model (CDM), per ANSI/ESDA/JEDEC JS-002 <sup>(2)</sup> | All pins       | ±2000 |

- (1) Tested in accordance with JEDEC Standard 22, Test Method A114-A.
- (2) Tested in accordance with JEDEC Standard 22, Test Method C101.

### 5.3 Dissipation Rating Table

| PACKAGE | T <sub>A</sub> ≤ 25°C POWER RATING | DERATING FACTOR <sup>(1)</sup> ABOVE T <sub>A</sub> = 25°C | T <sub>A</sub> = 70°C POWER RATING | T <sub>A</sub> = 85°C POWER RATING |
|---------|------------------------------------|------------------------------------------------------------|------------------------------------|------------------------------------|
| D       | 1080 mW                            | 8.7 mW/°C                                                  | 690 mW                             | 560 mW                             |
| N       | 1150 mW                            | 9.2 mW/°C                                                  | 736 mW                             | 598 mW                             |

- (1) This is the inverse of the junction-to-ambient thermal resistance when board-mounted and with no air flow.

### 5.4 Thermal Information

| THERMAL METRIC <sup>(1)</sup> |                                              | SOIC (D) | PDIP (N) | UNIT |
|-------------------------------|----------------------------------------------|----------|----------|------|
|                               |                                              | 16 Pins  | 16 Pins  |      |
| R <sub>θJA</sub>              | Junction-to-ambient thermal resistance       | 84.6     | 60.6     | °C/W |
| R <sub>θJC(top)</sub>         | Junction-to-case (top) thermal resistance    | 43.5     | 48.1     | °C/W |
| R <sub>θJB</sub>              | Junction-to-board thermal resistance         | 43.1     | 40.6     | °C/W |
| ψ <sub>JT</sub>               | Junction-to-top characterization parameter   | 10.4     | 27.5     | °C/W |
| ψ <sub>JB</sub>               | Junction-to-board characterization parameter | 42.8     | 40.3     | °C/W |
| R <sub>θJC(bot)</sub>         | Junction-to-case (bottom) thermal resistance | N/A      | N/A      | °C/W |

- (1) For more information about traditional and new thermal metrics, see the [Semiconductor and IC package thermal metrics](#) application report.

## 5.5 Recommended Operating Conditions

|                                       |                   | MIN  | NOM | MAX      | UNIT |
|---------------------------------------|-------------------|------|-----|----------|------|
| Supply voltage, $V_{CC}$              |                   | 4.75 | 5   | 5.25     | V    |
| Voltage at any bus terminal           | A, B              | -7   |     | 12       | V    |
| High-level input voltage, $V_{IH}$    | G, $\overline{G}$ | 2    |     | $V_{CC}$ | V    |
| Low-level input voltage, $V_{IL}$     |                   | 0    |     | 0.8      |      |
| Output current                        | Y                 | -8   |     | 8        | mA   |
| Operating free-air temperature, $T_A$ | SN75LBC173A       | 0    |     | 70       | °C   |
|                                       | SN65LBC173A       | -40  |     | 85       |      |

## 5.6 Electrical Characteristics

over recommended operating conditions

| PARAMETER        |                                                           |                                 | TEST CONDITIONS                                                                        |                                              | MIN  | TYP <sup>(1)</sup> | MAX | UNIT |
|------------------|-----------------------------------------------------------|---------------------------------|----------------------------------------------------------------------------------------|----------------------------------------------|------|--------------------|-----|------|
| V <sub>IT+</sub> | Positive-going differential input voltage threshold       |                                 | -7 V ≤ V <sub>CM</sub> ≤ 12 V (V <sub>CM</sub> = (V <sub>A</sub> + V <sub>B</sub> )/2) |                                              | -80  |                    | -10 | mV   |
| V <sub>IT-</sub> | Negative-going differential input voltage threshold       |                                 |                                                                                        |                                              | -200 | -120               |     |      |
| V <sub>HYS</sub> | Hysteresis voltage (V <sub>IT+</sub> - V <sub>IT-</sub> ) |                                 |                                                                                        |                                              | 40   |                    |     | mV   |
| V <sub>IK</sub>  | Input clamp voltage                                       |                                 | I <sub>I</sub> = -18 mA                                                                |                                              | -1.5 | -0.8               |     | V    |
| V <sub>OH</sub>  | High-level output voltage                                 |                                 | V <sub>ID</sub> = 200 mV, I <sub>OH</sub> = -8 mA                                      | See Figure 6-1                               | 2.7  | 4.8                |     | V    |
| V <sub>OL</sub>  | Low-level output voltage                                  |                                 | V <sub>ID</sub> = -200 mV, I <sub>OL</sub> = 8 mA                                      |                                              | 0.2  |                    | 0.4 |      |
| I <sub>OZ</sub>  | High-impedance-state output current                       |                                 | V <sub>O</sub> = 0 V to V <sub>CC</sub>                                                |                                              | -1   |                    | 1   | μA   |
| I <sub>I</sub>   | Line input current                                        |                                 | Other input at 0 V, V <sub>CC</sub> = 0 V or 5 V                                       | V <sub>I</sub> = 12 V                        |      |                    | 0.9 | mA   |
|                  |                                                           |                                 |                                                                                        | V <sub>I</sub> = -7 V                        | -0.7 |                    |     |      |
| I <sub>IH</sub>  | High-level input current                                  | Enable inputs G, $\overline{G}$ |                                                                                        |                                              |      |                    | 100 | μA   |
| I <sub>IL</sub>  | Low-level input current                                   |                                 |                                                                                        |                                              | -100 |                    |     | μA   |
| R <sub>I</sub>   | Input resistance                                          | A, B inputs                     |                                                                                        | 12                                           |      |                    |     | kΩ   |
| I <sub>CC</sub>  | Supply current                                            |                                 | V <sub>ID</sub> = 5 V                                                                  | G at 0 V, $\overline{G}$ at V <sub>CC</sub>  |      |                    | 20  | μA   |
|                  |                                                           |                                 | No load                                                                                | G at V <sub>CC</sub> , $\overline{G}$ at 0 V |      | 11                 | 16  | mA   |

(1) All typical values are at V<sub>CC</sub> = 5 V and 25°C.

## 5.7 Switching Characteristics

over recommended operating conditions

| PARAMETER           |                                                             | TEST CONDITIONS                               | MIN TYP <sup>(1)</sup> | MAX | UNIT |
|---------------------|-------------------------------------------------------------|-----------------------------------------------|------------------------|-----|------|
| t <sub>r</sub>      | Output rise time                                            | V <sub>ID</sub> = -3 V to 3 V, See Figure 6-2 | 2                      | 4   | ns   |
| t <sub>f</sub>      | Output fall time                                            |                                               | 2                      | 4   | ns   |
| t <sub>PLH</sub>    | Propagation delay time, low-to-high level output            |                                               | 9 12                   | 16  | ns   |
| t <sub>PHL</sub>    | Propagation delay time, high-to-low level output            |                                               | 9 12                   | 16  | ns   |
| t <sub>PZH</sub>    | Propagation delay time, high-impedance to high-level output | See Figure 6-3                                | 27                     | 38  | ns   |
| t <sub>PHZ</sub>    | Propagation delay time, high-level to high-impedance output |                                               | 7                      | 16  | ns   |
| t <sub>PZL</sub>    | Propagation delay time, high-impedance to low level output  | See Figure 6-4                                | 29                     | 38  | ns   |
| t <sub>PLZ</sub>    | Propagation delay time, low-level to high-impedance output  |                                               | 12                     | 16  | ns   |
| t <sub>sk(p)</sub>  | Pulse skew ( (t <sub>PLH</sub> - t <sub>PHL</sub> ) )       |                                               | 0.2                    | 1   | ns   |
| t <sub>sk(o)</sub>  | Output skew (see Note 4)                                    |                                               |                        | 2   | ns   |
| t <sub>sk(pp)</sub> | Part-to-part skew (see Note 5)                              |                                               |                        | 2   | ns   |

(1) All typical values are at V<sub>CC</sub> = 5 V and 25°C.

- Outputs skew (t<sub>sk(o)</sub>) is the magnitude of the time delay difference between the outputs of a single device with all of the inputs connected together.
- Part-to-part skew (t<sub>sk(pp)</sub>) is the magnitude of the difference in propagation delay times between any specified terminals of two devices when both devices operate with the same input signals, the same supply voltages, at the same temperature, and have identical packages and test circuits.

## 5.8 Typical Characteristics

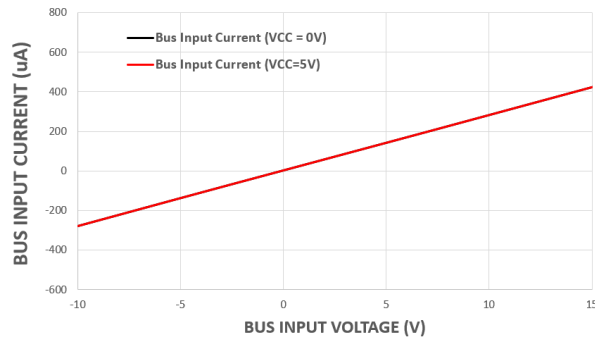


Figure 5-1. Bus Input Current vs Bus Input Voltage

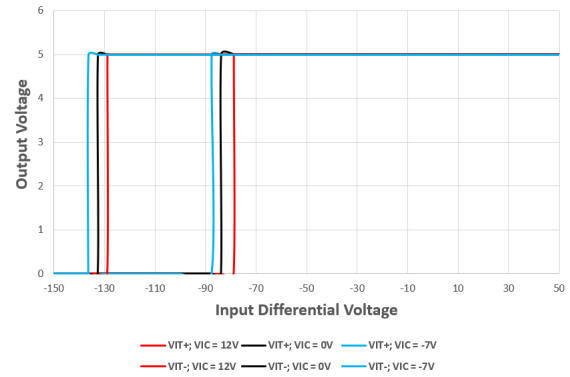


Figure 5-2. Output Voltage vs Differential Input Voltage

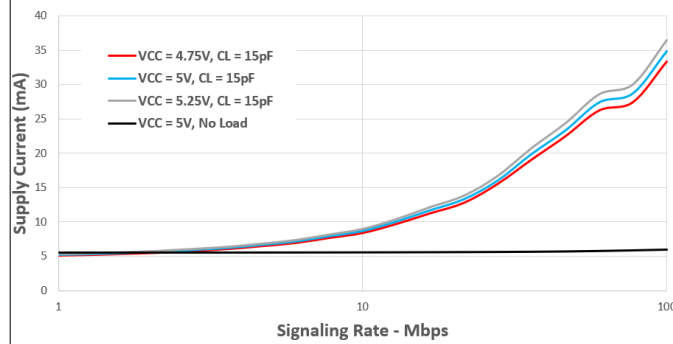


Figure 5-3. Supply Current vs Signaling Rate (All Four Channels)

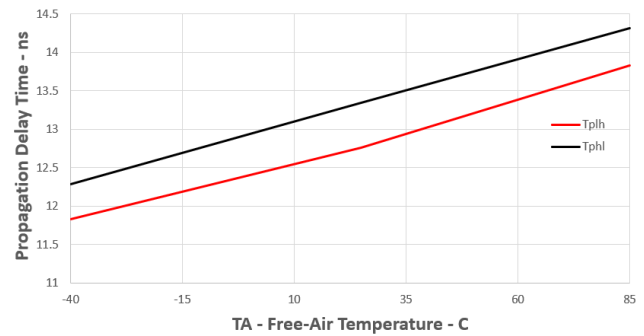


Figure 5-4. Propagation Delay Time vs Free-air Temperature

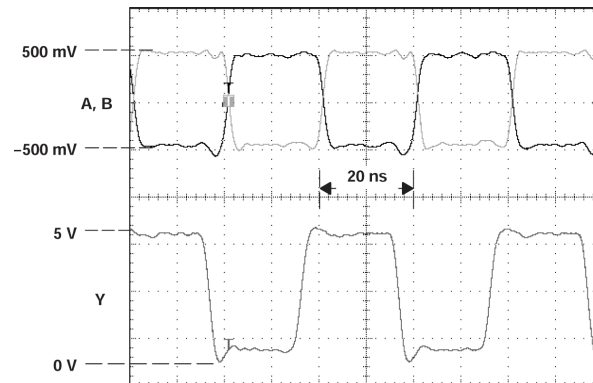


Figure 5-5. Receiver Inputs and Outputs, 50 Mbps Signaling Rate

## 6 Parameter Measurement Information

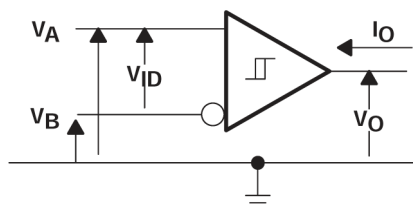
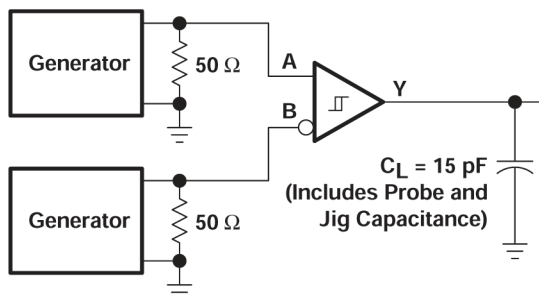


Figure 6-1. Voltage and Current Definitions



Generators: PRR = 1 MHz, 50% Duty Cycle,  
 $t_r < 6 \text{ ns}$ ,  $Z_O = 50 \Omega$

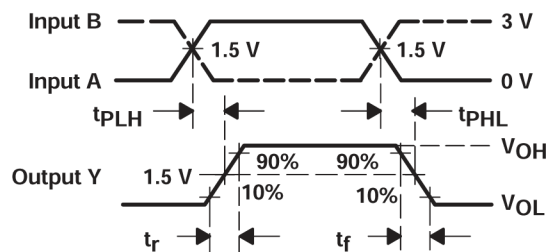
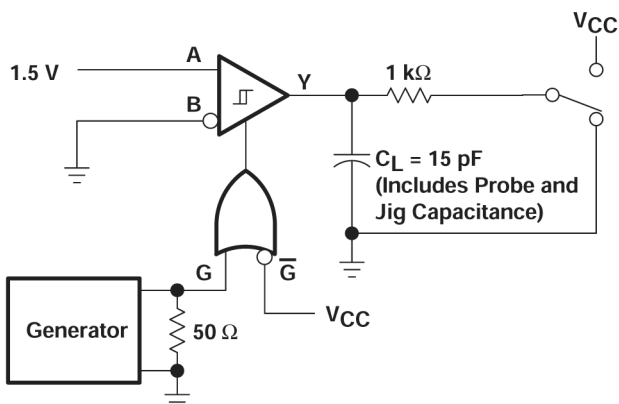


Figure 6-2. Switching Test Circuit and Waveforms



Generators: PRR = 1 MHz, 50% Duty Cycle,  
 $t_r < 6 \text{ ns}$ ,  $Z_O = 50 \Omega$

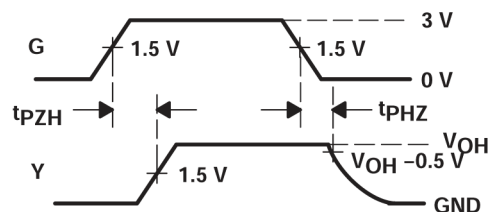
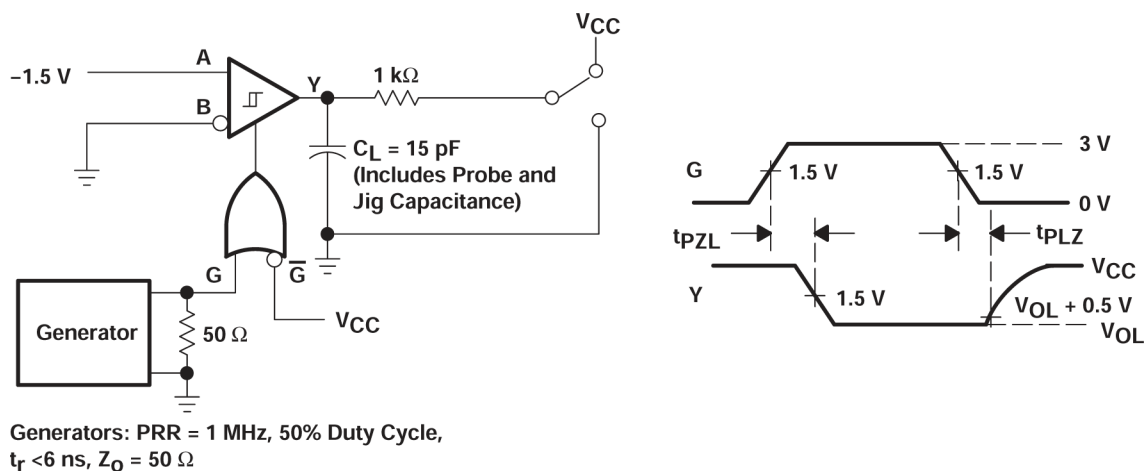
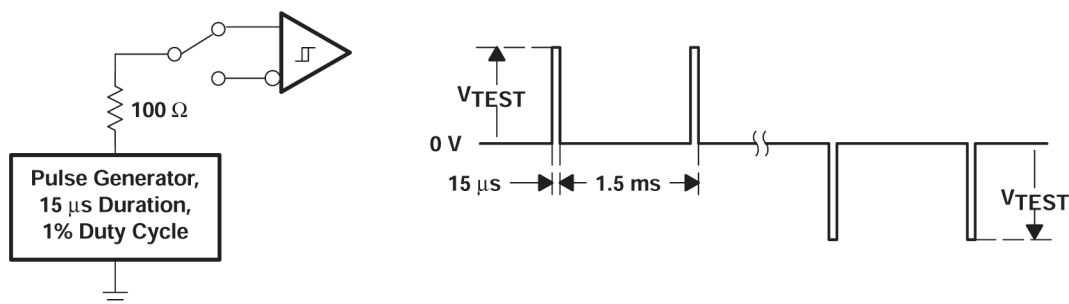


Figure 6-3. Test Circuit Waveforms,  $t_{PZH}$  and  $t_{PHZ}$





**Figure 6-4. Test Circuit Waveforms,  $t_{pZL}$  and  $t_{pLZ}$**



**Figure 6-5. Test Circuit and Waveform, Transient Over-Voltage Test**

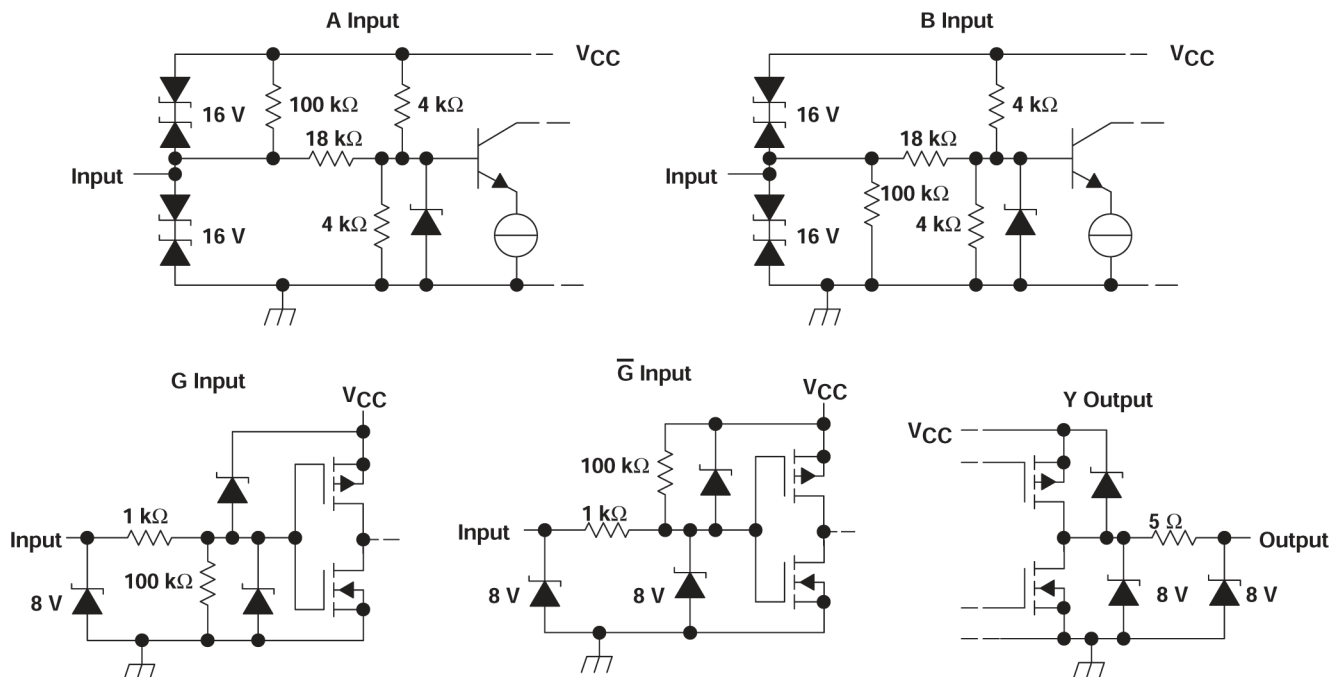
## 7 Detailed Description

### 7.1 Device Functional Modes

**Table 7-1. Functional Table (Each Receiver)**

| DIFFERENTIAL INPUTS A – B ( $V_{ID}$ ) | ENABLES <sup>(1)</sup> |           | OUTPUT Y |
|----------------------------------------|------------------------|-----------|----------|
|                                        | G                      | $\bar{G}$ |          |
| $V_{ID} \leq -0.2$ V                   | H                      | X         | L        |
|                                        | X                      | L         |          |
| $-0.2$ V $< V_{ID} < -0.01$ V          | H                      | X         | ?        |
|                                        | X                      | L         |          |
| $-0.01$ V $\leq V_{ID}$                | H                      | X         | H        |
|                                        | X                      | L         |          |
| X                                      | L                      | H         | Z        |
|                                        | OPEN                   | OPEN      |          |
| Short circuit                          | H                      | X         | H        |
|                                        | X                      | L         |          |
| Open circuit                           | H                      | X         | H        |

(1) H = high level, L = low level, X = irrelevant, Z = high impedance (off), ? = indeterminate



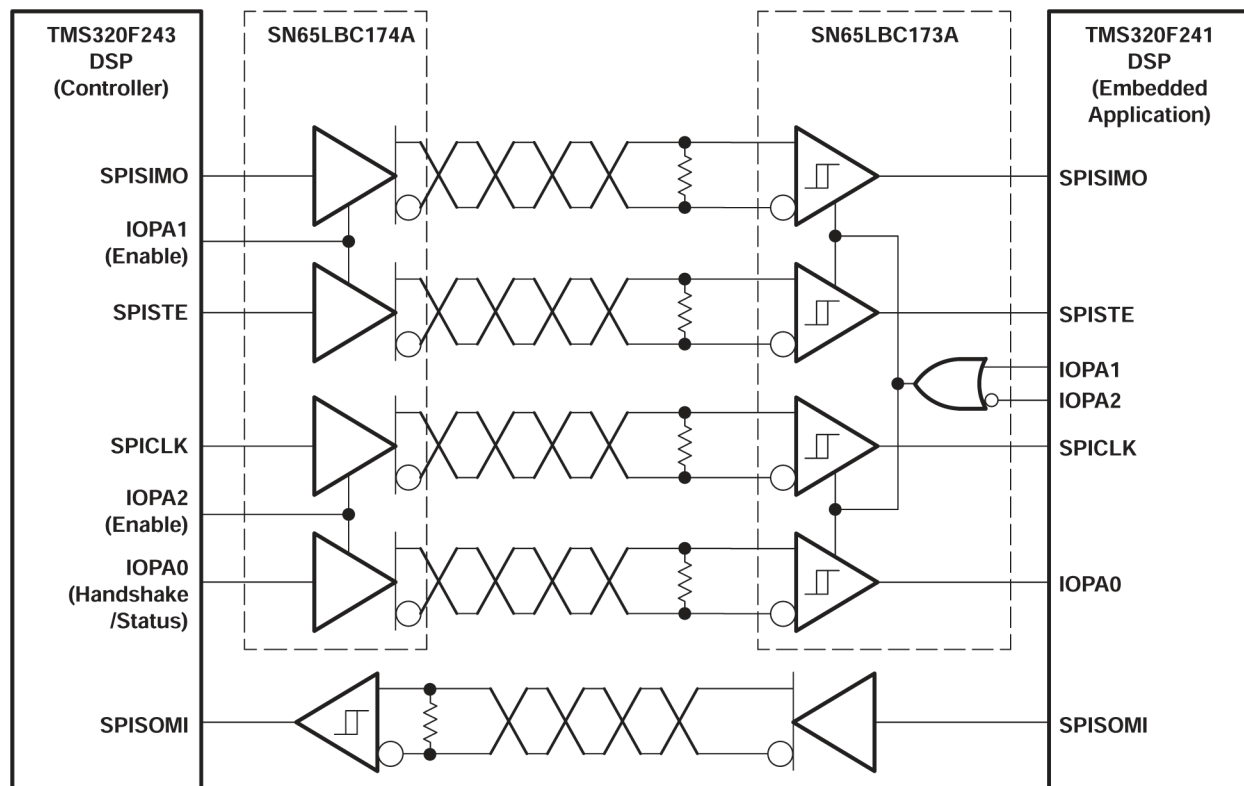
**Figure 7-1. Equivalent Input and Output Schematic Diagrams**

## 8 Application and Implementation

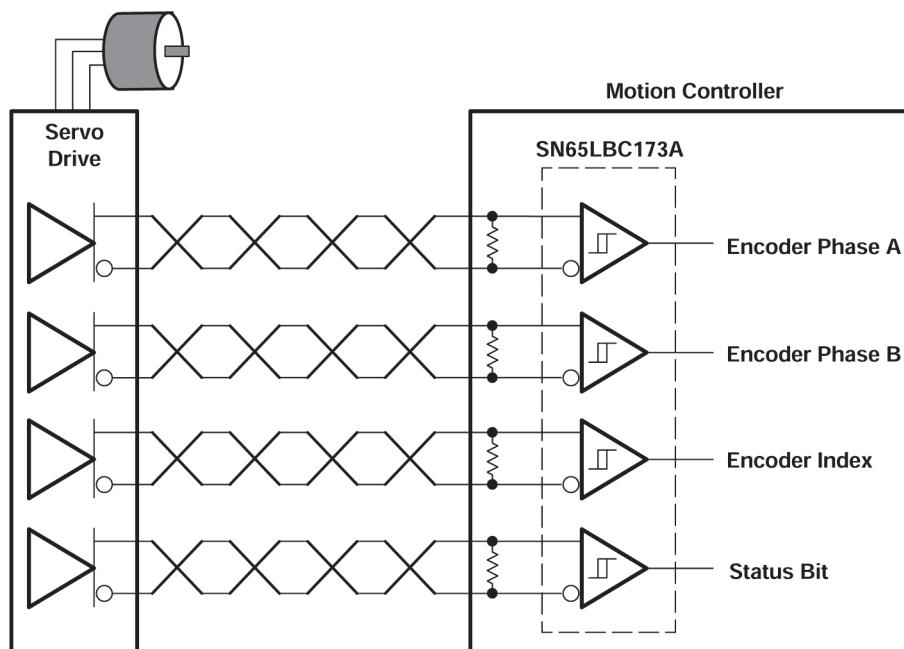
### Note

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes, as well as validating and testing their design implementation to confirm system functionality.

### 8.1 Typical Application



**Figure 8-1. Typical Application Circuit, DSP-to-DSP Link via Serial Peripheral Interface**



**Figure 8-2. Typical Application Circuit, High-Speed Servomotor Encoder Interface**

## 9 Device and Documentation Support

### 9.1 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on [ti.com](https://www.ti.com). Click on *Subscribe to updates* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

### 9.2 Support Resources

[TI E2E™ support forums](#) are an engineer's go-to source for fast, verified answers and design help — straight from the experts. Search existing answers or ask your own question to get the quick design help you need.

Linked content is provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's [Terms of Use](#).

### 9.3 Trademarks

TI E2E™ is a trademark of Texas Instruments.

All trademarks are the property of their respective owners.

### 9.4 Electrostatic Discharge Caution



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

### 9.5 Glossary

[TI Glossary](#) This glossary lists and explains terms, acronyms, and definitions.

## 10 Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

| <b>Changes from Revision B (April 2005) to Revision C (November 2023)</b>                             | <b>Page</b> |
|-------------------------------------------------------------------------------------------------------|-------------|
| • Changed the numbering format for tables, figures, and cross-references throughout the document..... | <b>1</b>    |

## 11 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

## PACKAGING INFORMATION

| Orderable part number         | Status<br>(1) | Material type<br>(2) | Package   Pins | Package qty   Carrier | RoHS<br>(3) | Lead finish/<br>Ball material<br>(4) | MSL rating/<br>Peak reflow<br>(5) | Op temp (°C) | Part marking<br>(6) |
|-------------------------------|---------------|----------------------|----------------|-----------------------|-------------|--------------------------------------|-----------------------------------|--------------|---------------------|
| <a href="#">SN65LBC173AD</a>  | Obsolete      | Production           | SOIC (D)   16  | -                     | -           | Call TI                              | Call TI                           | -40 to 85    | 65LBC173A           |
| <a href="#">SN65LBC173ADR</a> | Active        | Production           | SOIC (D)   16  | 2500   LARGE T&R      | Yes         | NIPDAU                               | Level-1-260C-UNLIM                | -40 to 85    | 65LBC173A           |
| SN65LBC173ADR.A               | Active        | Production           | SOIC (D)   16  | 2500   LARGE T&R      | Yes         | NIPDAU                               | Level-1-260C-UNLIM                | -40 to 85    | 65LBC173A           |
| SN65LBC173ADRG4               | Active        | Production           | SOIC (D)   16  | 2500   LARGE T&R      | Yes         | NIPDAU                               | Level-1-260C-UNLIM                | -40 to 85    | 65LBC173A           |
| SN65LBC173ADRG4.A             | Active        | Production           | SOIC (D)   16  | 2500   LARGE T&R      | Yes         | NIPDAU                               | Level-1-260C-UNLIM                | -40 to 85    | 65LBC173A           |
| <a href="#">SN65LBC173AN</a>  | Active        | Production           | PDIP (N)   16  | 25   TUBE             | Yes         | NIPDAU                               | N/A for Pkg Type                  | -40 to 85    | 65LBC173A           |
| SN65LBC173AN.A                | Active        | Production           | PDIP (N)   16  | 25   TUBE             | Yes         | NIPDAU                               | N/A for Pkg Type                  | -40 to 85    | 65LBC173A           |
| <a href="#">SN75LBC173ADR</a> | Obsolete      | Production           | SOIC (D)   16  | -                     | -           | Call TI                              | Call TI                           | 0 to 70      | 75LBC173A           |
| <a href="#">SN75LBC173AN</a>  | Obsolete      | Production           | PDIP (N)   16  | -                     | -           | Call TI                              | Call TI                           | 0 to 70      | 75LBC173A           |

<sup>(1)</sup> **Status:** For more details on status, see our [product life cycle](#).

<sup>(2)</sup> **Material type:** When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

<sup>(3)</sup> **RoHS values:** Yes, No, RoHS Exempt. See the [TI RoHS Statement](#) for additional information and value definition.

<sup>(4)</sup> **Lead finish/Ball material:** Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

<sup>(5)</sup> **MSL rating/Peak reflow:** The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

<sup>(6)</sup> **Part marking:** There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

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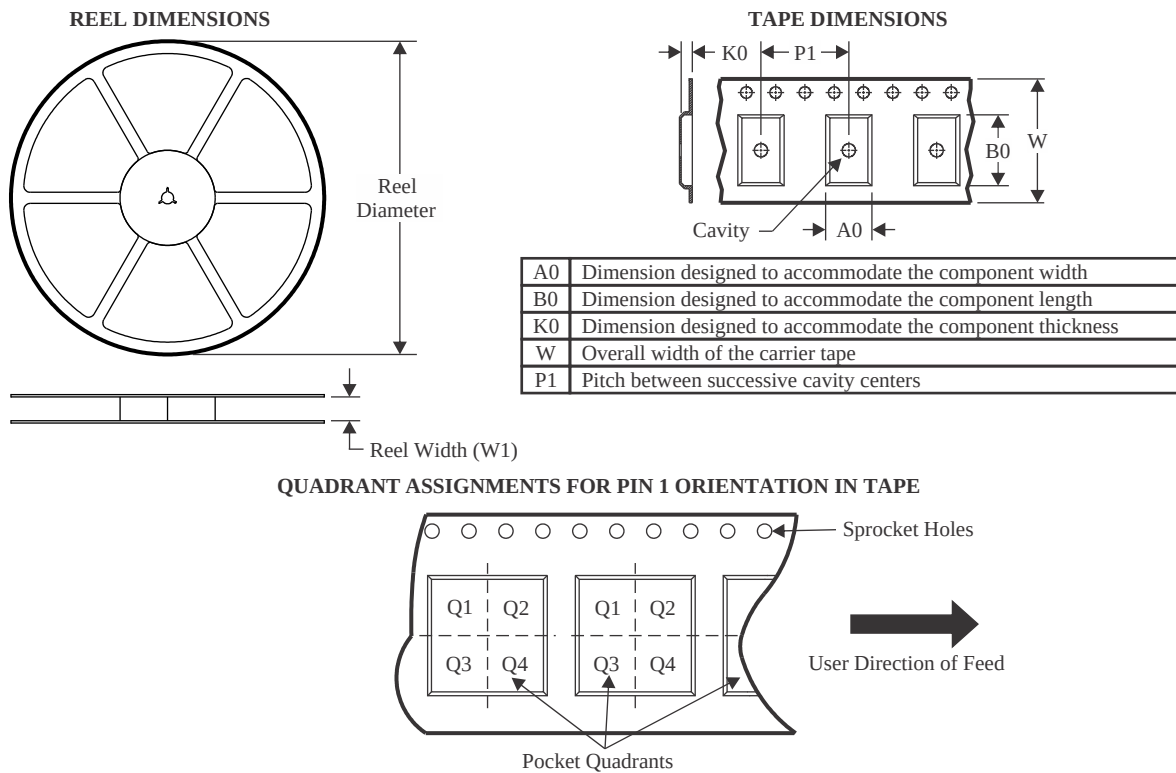
**OTHER QUALIFIED VERSIONS OF SN65LBC173A :**

- Enhanced Product : [SN65LBC173A-EP](#)

NOTE: Qualified Version Definitions:

- Enhanced Product - Supports Defense, Aerospace and Medical Applications

## TAPE AND REEL INFORMATION

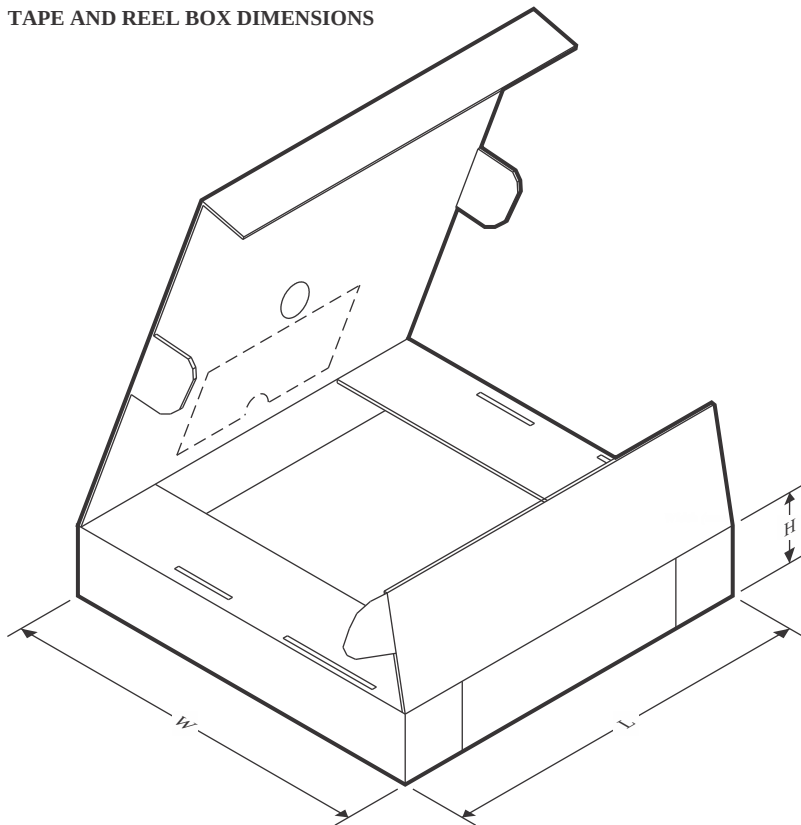


\*All dimensions are nominal

| Device          | Package Type | Package Drawing | Pins | SPQ  | Reel Diameter (mm) | Reel Width W1 (mm) | A0 (mm) | B0 (mm) | K0 (mm) | P1 (mm) | W (mm) | Pin1 Quadrant |
|-----------------|--------------|-----------------|------|------|--------------------|--------------------|---------|---------|---------|---------|--------|---------------|
| SN65LBC173ADR   | SOIC         | D               | 16   | 2500 | 330.0              | 16.4               | 6.5     | 10.3    | 2.1     | 8.0     | 16.0   | Q1            |
| SN65LBC173ADRG4 | SOIC         | D               | 16   | 2500 | 330.0              | 16.4               | 6.5     | 10.3    | 2.1     | 8.0     | 16.0   | Q1            |



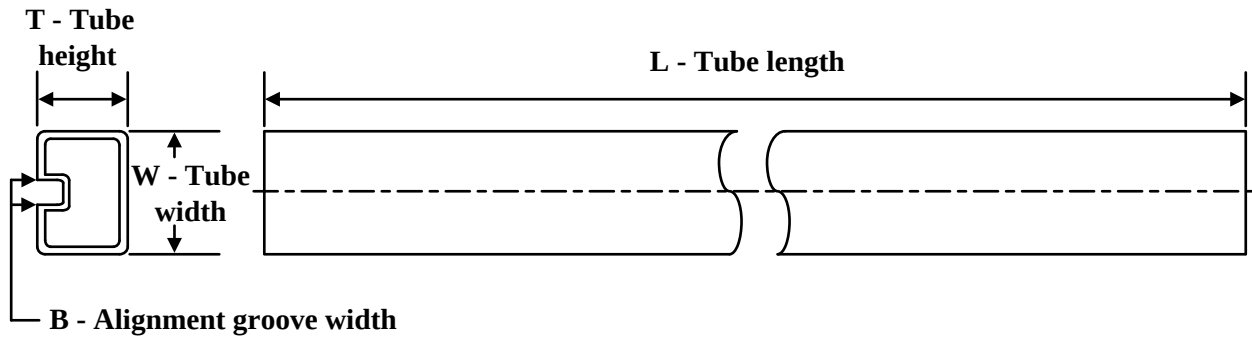
## TAPE AND REEL BOX DIMENSIONS



\*All dimensions are nominal

| Device          | Package Type | Package Drawing | Pins | SPQ  | Length (mm) | Width (mm) | Height (mm) |
|-----------------|--------------|-----------------|------|------|-------------|------------|-------------|
| SN65LBC173ADR   | SOIC         | D               | 16   | 2500 | 353.0       | 353.0      | 32.0        |
| SN65LBC173ADRG4 | SOIC         | D               | 16   | 2500 | 353.0       | 353.0      | 32.0        |

## TUBE

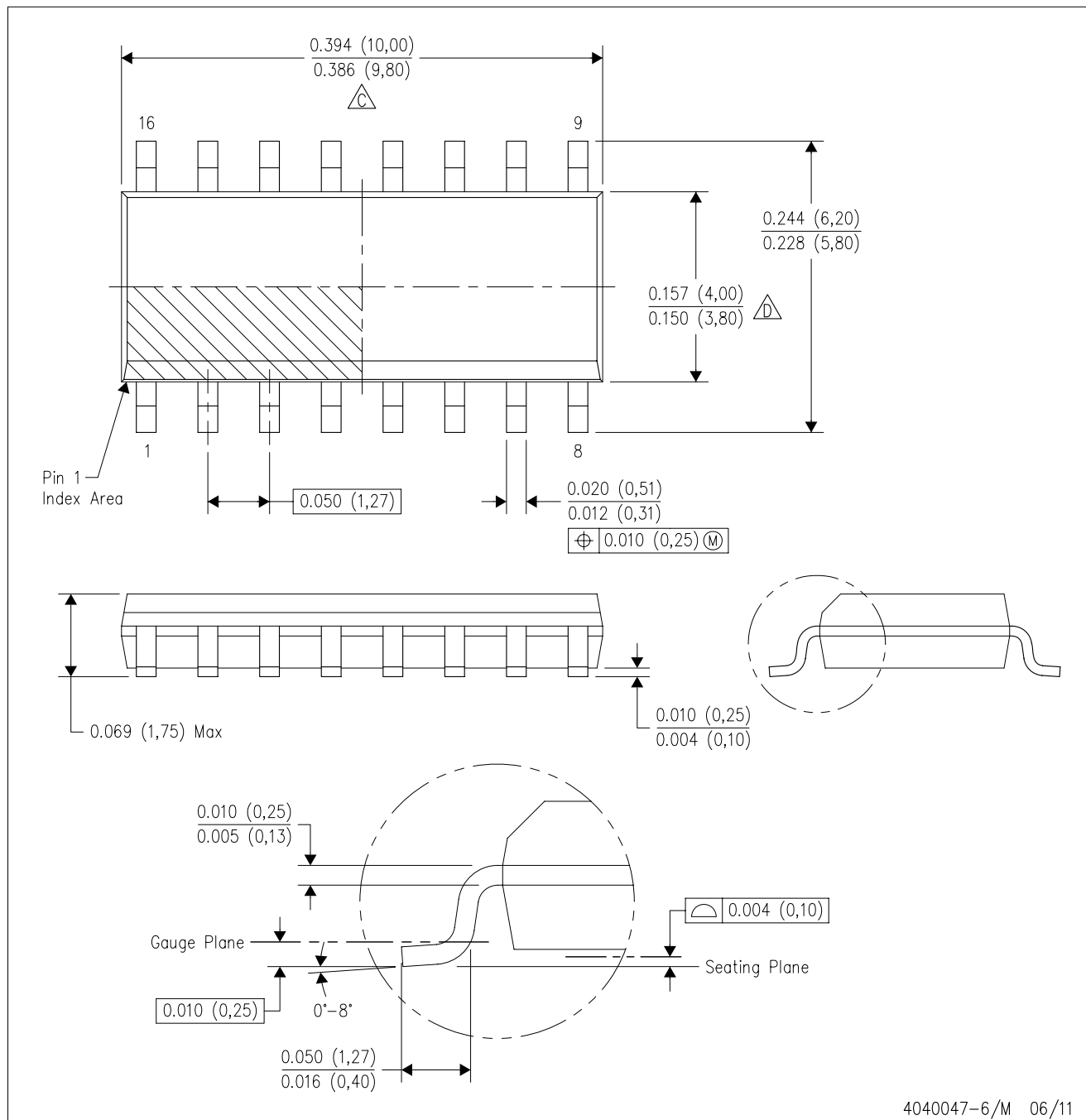


\*All dimensions are nominal

| Device         | Package Name | Package Type | Pins | SPQ | L (mm) | W (mm) | T (μm) | B (mm) |
|----------------|--------------|--------------|------|-----|--------|--------|--------|--------|
| SN65LBC173AN   | N            | PDIP         | 16   | 25  | 506    | 13.97  | 11230  | 4.32   |
| SN65LBC173AN.A | N            | PDIP         | 16   | 25  | 506    | 13.97  | 11230  | 4.32   |

D (R-PDSO-G16)

PLASTIC SMALL OUTLINE



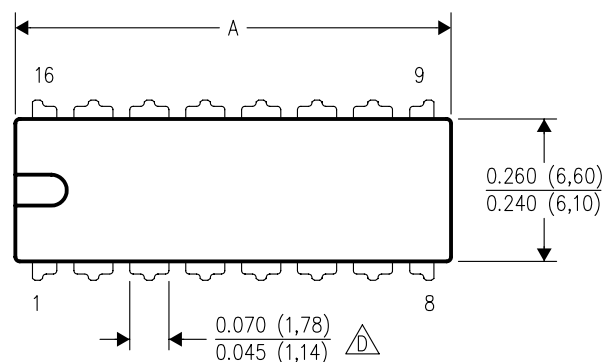
4040047-6/M 06/11

- NOTES:
- A. All linear dimensions are in inches (millimeters).
  - B. This drawing is subject to change without notice.
  - C. Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
  - D. Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
  - E. Reference JEDEC MS-012 variation AC.

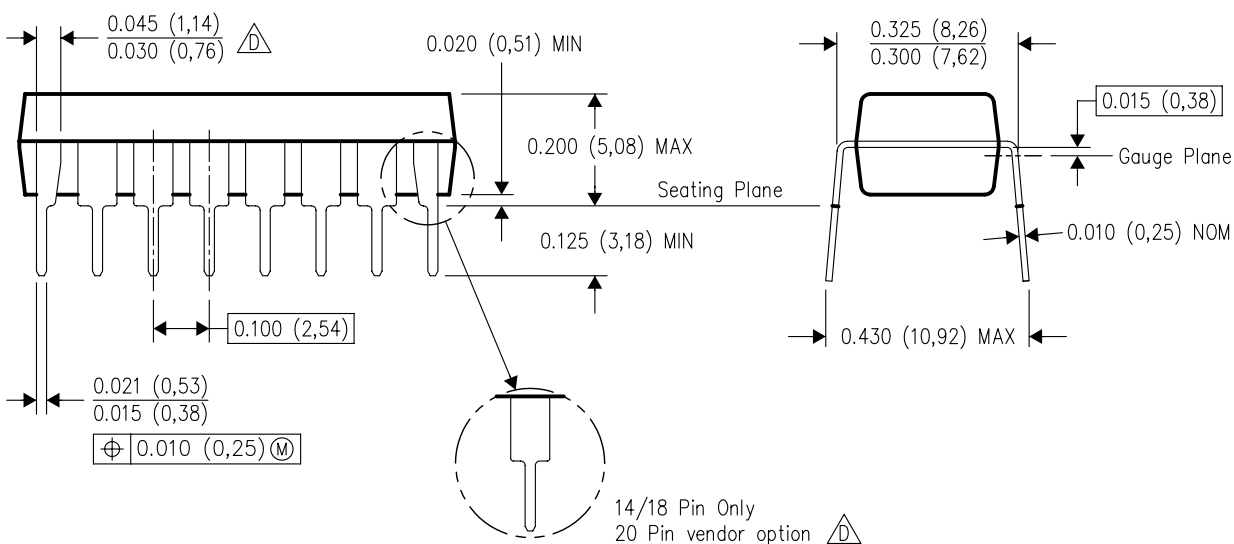
N (R-PDIP-T\*\*)

16 PINS SHOWN

## PLASTIC DUAL-IN-LINE PACKAGE



| PINS **<br>DIM      | 14               | 16               | 18               | 20               |
|---------------------|------------------|------------------|------------------|------------------|
| A MAX               | 0.775<br>(19,69) | 0.775<br>(19,69) | 0.920<br>(23,37) | 1.060<br>(26,92) |
| A MIN               | 0.745<br>(18,92) | 0.745<br>(18,92) | 0.850<br>(21,59) | 0.940<br>(23,88) |
| MS-001<br>VARIATION | AA               | BB               | AC               | AD               |



4040049/E 12/2002

NOTES:

- A. All linear dimensions are in inches (millimeters).  
B. This drawing is subject to change without notice.
-  Falls within JEDEC MS-001, except 18 and 20 pin minimum body length (Dim A).  
 The 20 pin end lead shoulder width is a vendor option, either half or full width.

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